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Visualized measurement of the electric field in large aperture LiNbO$_3$ crystal by digital holographic interferometry

Zhiyong Lu, Jianfeng Sun, Yu Zhou, Ning Zhang, Zhiwei Sun, and Liren Liu

Key Laboratory of Space Laser Communication and Detection Technology, Shanghai Institute of Optics and Fine Mechanics, Chinese Academy of Sciences, Shanghai 201800, China

*Corresponding author: luzhiyong15@126.com

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The electric field distribution in LiNbO$_3$ crystal under different electrode shape is presented by using the digital holographic interferometry. Three configurations of phase modulator including the rectangular electrode type, single-triangle electrode type, and dual-triangle electrode type are performed in this experiment. The nonuniform electric field distribution in these phase modulators are observed and the electric field increases with voltage increasing. The digital holographic interferometry with high electro-optic effect improves the measurement precision. The digital holographic interferometry provides an effective way for studying the electric field distribution. Such in situ quantitative analysis of electric field distribution is a key to optimizing electrode shape.

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The property of electric-field tunable refractive index, also called the electro-optic effect, is currently of great interest for light modulation at high operating speed (intrinsic response speeds of >100 GHz). Electro-optic modulation technology is widely used in many devices, such as optical communication devices, switches, optical scanners, etc., to perform various functions in the transmission and processing of electrical and optical signals. In high power laser application, in order to obtain high quality and high power laser, large aperture electro-optic modulator is used to control and correct distorted laser phase. The laser energy is too high, waveguide electro-optic modulator would have nonlinear effect and thus be less paid attention to. So the transversal area of the modulator must increase with the increasing energy correspondingly. The electric field distribution in large aperture modulators would change and urgently need to be measured.

Laser beam scanner based on electro-optic modulation possesses triangular up-and-down electrode structure. The electro-optic effect controls the refractive index variation in the electrode area and makes the transmission beam obtain the gradient phase distribution. It is very useful in down-looking synthetic aperture imaging ladar. However, since the index change is typically small, high voltage has to be applied. With the increase of applied voltage, the electric field integral along the beam propagation direction present gradient distribution. Then, the spatial phase distribution could be controlled accurately.

In recent years, digital holographic interferometry has been widely used to measure the acoustic levitation field, refractive index distribution, effective crystal internal field, laser-induced domain nucleation, MEMS, and so on. Tran et al. primarily measured the surface discharge distribution with low coefficient. Lo et al. measured the GaAs semi-insulating surface property with CW electro-optic probing, but his set up is very complicated and low sensitive. $\gamma_{33}$ is the largest electro-optic coefficient in LiNbO$_3$ crystal, and is about 3 times of $\gamma_{13}$ when illuminated by extraordinary light. Phase modulation is very obvious to using the extraordinary s-polarized light with an applied electric field. It is widely used in different kinds of modulation.

In this Letter, three types of electrode shape were produced. And the extraordinary s-polarized light was used. The phase distribution of LiNbO$_3$ crystal under the three types of electrode was obtained. The electric field integral along the beam propagation direction were reconstructed by using the digital holographic interferometry.

Figure 1 shows the experimental set-up. A He–Ne laser beam ($\lambda = 632.8$ nm) is expanded and collimated through a reversed telescope. The beam from the reversed telescope propagates through the half-wave plate (HWP) and polarization beam splitter (PBS), then the beam is equally divided by the PBS into two beams with orthogonal polarizations, which constitutes a polarization Mach–Zehnder interferometer configuration. Lenses $L_1$ and $L_2$ form 4f systems, respectively. The rear face of LiNbO$_3$ crystal is placed at the front focal plane of lens $L_1$. The horizontally polarized beam and the vertically polarized beam are combined by the second PBS. The combined beam passes through the analyzer generating interference pattern collected by the CCD camera. The high sensitive photosensing plane of the CCD camera with a $720 \times 576$ pixel array (about 8.333 $\mu$m/pixel pitch) and is placed at the rear focus plane of lens $L_2$ to record the image holograms. The vertically polarized beam propagating through the LiNbO$_3$ crystal sample acts as the object beam, and the
other beam as the reference beam. The polarizations of the vertically polarized beam are parallel to the $z$ axis of the LiNbO$_3$ crystal, to detect the extraordinary index changes with different applied electric field. The electro-optic coefficient of extraordinary polarized light $\gamma_{33}$ is larger than other electro-optic coefficient. The refractive index changes is more obvious when the $e$-polarized light propagates through the phase modulator under the $z$ axis electric field.

In the experimental process, first, the horizontally polarized beam and the vertically polarized beam are coaxially recombined. The propagation direction of the horizontally polarized light was adjusted. The angle between the horizontally polarized beam and the vertically polarized beam is about 1°. Secondly, the electrode was closed to the crystal along the $z$ direction, and a adjustable voltage was be used. Finally, the CCD camera recorded a frame per 50 V. The largest voltage is 3200 V.

The sample holder used for the experiments is illustrated by Fig. 2. The LiNbO$_3$ crystal sample, which is a $z$-cut with 4-mm-thick, 12-mm-width, 60-mm-length. A 4 mm × 4 mm rectangular stop is placed in front of the crystal. In the experiment, We made three types of electrode shapes including rectangular electrode type, single-triangle electrode type and dual-triangle electrode type to supply external field. The rectangle electrode is made of copper with 0.1-mm-thick, 12-mm-width, 60-mm-length, the triangle electrode is also made of copper with 0.1-mm-thick, 10-mm-width, 60-mm-length. The electrode connection of the LiNbO$_3$ is showed by Fig. 2. The dynamic phase-mapping in LiNbO$_3$ crystal phase modulators under different applied voltage are recorded, then the electric field distribution could be reconstructed from the phase maps.

In the case of the digital holographic interferometry the intensity of the hologram on the CCD plane is

$$i(x, z) = a(x, z) + b(x, z) \exp(j\varphi(x, z)) \exp(-j2\pi f_{0z}x)$$
$$+ b'(x, z) \exp(-j\varphi(x, z)) \exp(j2\pi f_{0z}x),$$ (1)

where $a(x, z)$ is the background illumination, $b(x, z)$ is the amplitude modulation of the fringes, $\varphi(x, z)$ is the phase of the test object, $f_{0z}$ is the spatial frequency, and $c(x, z) = b(x, z) \exp(j\varphi(x, z))$. Then, applying the Fourier transform we will have

$$I(\xi, \eta) = A(\xi, \eta) + C_{+1}(\xi - f_{0z}, \eta) + C_{-1}(\xi + f_{0z}, \eta),$$ (2)

where $A(\xi, \eta)$ is the spectrum of the background illumination, $C_{+1}(\xi - f_{0z}, \eta)$ and $C_{-1}(\xi + f_{0z}, \eta)$ contain the spectra of the deformed object. In order to retrieve the phase information, the filtering, shifting and inverse Fourier transform are carried out from the following equations

$$c(x, z) = F^{-1}\{C_{+1}(\xi, \eta)\},$$ (3)
$$\varphi(x, z) = \arctan\left(\frac{\text{Im}[c(x, z)]}{\text{Re}[c(x, z)]}\right).$$ (4)

From the Eq. (4), we can obtain the corresponding wrapped phase distribution, then Branch-Cut Method is used to unwrap the object phase. In our experiment, the extraordinary index of LiNbO$_3$ crystal is controlled by the external electric field. In the absence of an electric field, the extraordinary index of LiNbO$_3$ crystal is constant. However, an electric field across the LiNbO$_3$ crystal along the $z$ direction would change the refractive index. The changes induce the phase retardation of the normally incident plane wave. For a LiNbO$_3$ crystal, the phase retardation between the waves passing through (in $y$ direction) in its two different states can be described by $\Delta \varphi(x, z) = (2\pi/\lambda)\Delta L(x, z)$, The optical path difference $\Delta L(x, z)$ is generally described as a line integral of the refractive index variation $\Delta L(x, z) = \int \Delta n(x, y, z) dy$, where $\Delta n(x, y, z) = n(x, y, z) - n_0$ and $n_0$ and $n(x, y, z)$ denote the initial and changed refractive indexes, respectively. Once obtained, $\Delta n(x, y, z)$ can be further used for calculating the electric field distribution. The incident beam pass through the LiNbO$_3$, in a cross section, the relationship of the phase retardation versus the change of the refractive index induced by the external electric field is expressed as
\[
\varphi(x, z) = \frac{2\pi}{\lambda} \int_0^L \left[n(x, y, z) - n_0\right] \, dy.
\]

Under the external electric field, the refractive index is changed as
\[
\Delta n = n(x, y, z) - n_0 = \frac{1}{2} n_0^2 \gamma_{33} E_z.
\]

So the phase distribution of the LiNbO\(_3\) crystal under the external electric field is
\[
\varphi(x, z) = \frac{2\pi}{\lambda} \int_0^L \left[\frac{1}{2} n_0^2 \gamma_{33} E(x, y, z)\right] \, dy.
\]

From above analysis, it is known that the refractive index distribution of the LiNbO\(_3\) crystals can be converted into the phase distribution of the object wavefront.

For the parallel electrodes applied on the surface of the cuboid LiNbO\(_3\) crystal, the line integral of the electric field distribution can be obtained by
\[
\int_0^L E(x, y, z) \, dy \approx E(x, z) L,
\]
where \(E(x, z)\) is the equivalent electric field distribution. Meanwhile, the electric field distribution \(E(x, z)\) is different in the three electrode types. The electric field under the rectangular electrode is \(U/h\), which is a constant. For the triangle electrode, the electric field distribution lies on the part crystal under the electrode. Triangular electrode regions with different indices of refraction are created with an applied voltage via the electro-optic effect. This modulator and linear gradient scanners have the same performance if they have the same device dimension and maximum index difference. So the line integral of the electric field distribution is equivalent to the gradient electric field, which is increasing linearly from up to down. The electric field distribution is about \(E(x, z) \approx k (U/h)(x/D)\), \((k = 1, 2)\), where \(k\) is related to the number of triangle electrode. For the dual-triangle electrode, two triangular electrode regions are defined by opposite voltage orientations in a single LiNbO\(_3\) crystal, so the line integral of the electric field distribution is about two times than single-triangle electrode. The visualized measurement of the electric field was demonstrated by the following experiment.

Dynamic electric field integral along the beam propagation direction under the rectangular electrode was measured at different applied voltages. Figure 3 shows the selected sequence of reconstructed electric field integral along the beam propagation direction during the increasing voltage applied on the LiNbO\(_3\) crystal. As can be observed, the electric field integral distribution are flat and smooth at the center, and is more uneven far away from the center. With the increase of the applied voltage, the electric field integral distribution bends more seriously, which means that index changes under the applied field are not all uniform. One reason is the initial refractive indexes are nonuniform. Another mostly possible reason is that the limited size of the electrode induces complicated fringing field effect, in which surface discharge distribution is not uniform, with more charge distribution on the edge of the electrode. Compare with the traditional numerical calculation in fringing field effect, this newly proposed approach could provide simultaneous information about the edge-effect and in situ monitoring the electric field distribution in crystals. In practical applications, this method can be used to optimize the size and shape of the electrode, and then make a quality phase modulation.

Electro-optic deflector with triangular electrode would cause the transmission beam deflection at the interface, so it is widely used in the electro-optic deflector. The linear phase shift of the beam in the deflector makes the beam deflect in the far field. When the single-triangle electrode was made on the face of the LiNbO\(_3\) crystal, only the refractive index of the LiNbO\(_3\) under the triangle electrode could be changed, and the phase retardation is not symmetrical, resulting in the beam translation in addition to the deflection. Moreover, high external electric field causes additional nonuniform electric field space distribution except the linear one. Figure 4 shows the selected sequence of reconstructed electric field integral distributions during the increasing applied voltage in the LiNbO\(_3\) crystal. As shown by Fig. 4, the electric field integral distributions generate linear change along the \(x\) direction, but we can also find some nonuniform phase changes on the edge of the electrode. With the increase of the applied voltage, the external electric field integral distribution becomes more distorted, bending more seriously.

Electro-optic deflector with dual-triangular electrode could achieve larger scanner angle, resulting from the more obvious linear phase shift. In this section, the electric field integral along the beam propagation direction under various applied voltage is also achieved by polarized digital holographic interferometry in LiNbO\(_3\) crystal under the dual-triangle electrode. Figure 5 shows the selected sequence of electric field integral distributions
In conclusion, the digital holographic interferometry is proposed to monitor and calculate the electric field integral distribution along the beam propagation direction. Dynamic nonuniform electric field integral distribution in LiNbO$_3$ phase modulation under three types of electrode and different applied voltage are measured. Electric field integral distribution under the rectangular electrode has higher value on the edge of the electrode and lower value in the center of the electrode. The higher applied voltage, the more distorted electric field integral distribution. Such electric field integral distribution is a key to optimizing electrode shape. In the future, we can receive interference pattern in different incident angle by rotating the LiNbO$_3$ crystal. Then the line integral of the electric field in different incident angle would be obtained using above method. At last, three-dimensional electric field distribution would be reconstructed by Radon–Fourier transform which is widely used in medical CT technology. This is our next major work.

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References


Fig. 4. Selected sequence of reconstructed electric field integral distributions under different applied voltages in the LiNbO$_3$ crystal with single-triangle electrode. The applied voltage is (a) 800, (b) 1600, (c) 2400, and (d) 3200 V.

Fig. 5. Selected sequence of reconstructed electric field integral distributions under different applied voltages in the LiNbO$_3$ crystal with dual-triangle electrode. The applied voltage is (a) 800, (b) 1600, (c) 2400, and (d) 3200 V.